

S/N 10/081,818

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PATENT

Applicant: Jerome M. Eldridge et al.

Examiner: Phuc Dang

Serial No.: 10/081,818

Group Art Unit: 2818

Filed: February 20, 2002

Docket No.: 1303.045USP

ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW
ASYMMETRICAL TUNNEL BARRIER INTERPOLY INSULATORS

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AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Commissioner for Patents
Washington, D.C. 20231

This paper is in response to the Office Action mailed on January 2, 2003. Please amend
the above-identified patent application as follows.

09/17/2003 CRPAWS 01/07/2003 10061818
01 FC:2776

IN THE TITLE

Please amend the title throughout the USPTO records to read “ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW ASYMMETRICAL TUNNEL BARRIER INTERPOLY INSULATORS”.

